# NSN 5962-01-339-6330

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Overall	Length:
Overall	Lengui.

1.290 inches

**Overall Height:** 

0.425 inches

## **Body Length:**

1.290 inches

### Body Width:

Between 0.500 inches and 0.610 inches

#### **Body Height:**

Between 0.150 inches and 0.210 inches

## **Maximum Power Dissipation Rating:**

950.0 milliwatts

**Operating Tempurature Range:** 

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

W/active pull-up and high impedance and 3-state output and monolithic and bipolar and schottky

Inclosure Material:

Ceramic

**Inclosure Configuration:** 

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

12 input

## **Case Outline Source And Designator:**

D-3 mil-m-38510

## **Current Rating Per Characteristic:**

170.00 milliamperes reverse current, dc absolute

#### **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

# Time Rating Per Chacteristic:

125.00 nanoseconds access

# Memory Device Type:

Prom

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

24 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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